

R-C Thermal Model Parameters

DESCRIPTION

The parametric values in the R-C thermal model have been derived using curve-fitting techniques. R-C values for the electrical circuit in the Foster/tank and Cauer/filter configurations are included. When implemented in P-SPICE, these values have matching characteristic curves to the single-pulse transient thermal impedance curves for the MOSFET.

These RC values can be used in the P-SPICE simulation to evaluate the thermal behavior of the MOSFET junction temperature under a defined power profile. These techniques are described in application note AN609, "Thermal Simulation of Power MOSFETs on the P-SPICE Platform".

R-C THERMAL MODEL FOR TANK CONFIGURATION



R-C VALUES FOR TANK CONFIGURATION			
THERMAL RESISTANCE (°C/W)			
Junction to	Ambient	Case	Foot
RT1	24.9998	828.7780 m	N/A
RT2	28.9808	773.3808 m	N/A
RT3	11.6530	300.5467 m	N/A
RT4	4.1921	1.4008	N/A
THERMAL CAPACITANCE (Joules/°C)			
Junction to	Ambient	Case	Foot
CT1	1.5636	21.9176 m	N/A
CT2	4.5631	865.4559 u	N/A
CT3	99.9148 m	71.9584 m	N/A
CT4	8.5036 m	12.4943 m	N/A

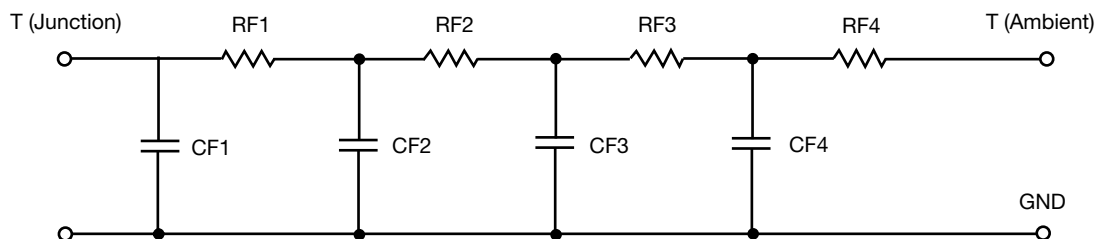
Note

N/A indicates not applicable

This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits.



R-C THERMAL MODEL FOR FILTER CONFIGURATION



R-C VALUES FOR FILTER CONFIGURATION			
THERMAL RESISTANCE (°C/W)			
Junction to	Ambient	Case	Foot
RF1	3.4789	557.1881 m	N/A
RF2	11.0804	866.9523 m	N/A
RF3	19.4867	807.5158 m	N/A
RF4	35.9540	1.0685	N/A
THERMAL CAPACITANCE (Joules/°C)			
Junction to	Ambient	Case	Foot
CF1	5.1652 m	570.4000 u	N/A
CF2	53.9763 m	2.3094 m	N/A
CF3	612.4319 m	4.7749 m	N/A
CF4	1.8616	5.5774 m	N/A

Note

N/A indicates not applicable

